tary outputs.

## 

### Low-Power, 1% Accurate, Dual-/Triple-/Quad-Level **Battery Monitors in Small TDFN and TQFN Packages**

### **General Description**

The MAX6782-MAX6790 are low-power, 1% accurate,

dual-/triple-/quad-level battery monitors offered in small

TDFN and TQFN packages. These devices are ideal for

monitoring single lithium-ion (Li+) cells, or multicell alkaline/NiCd/NiMH power sources. These devices feature

fixed and adjustable hysteresis options to eliminate out-

The MAX6782/MAX6783 offer four battery monitors in a

single package with factory-set (0.5%, 5%, 10%) or adjustable hysteresis. The MAX6784/MAX6785 provide

three battery monitors with factory-set (0.5%, 5%, 10%)

or adjustable hysteresis. The MAX6786/MAX6787/

MAX6788 offer two battery monitors with external inputs

for setting the rising and falling thresholds, allowing external hysteresis control. The MAX6789/MAX6790 fea-

ture guad-level overvoltage detectors with complemen-

The MAX6782–MAX6790 are offered with either open-drain

or push-pull outputs. The MAX6782/MAX6784/MAX6786/ MAX6789 are available with push-pull outputs while the MAX6783/MAX6785/MAX6787/MAX6790 are available with open-drain outputs. The MAX6788 is available with one open-drain output and one push-pull output (see the Selector Guide). This family of devices is offered in spacesaving TDFN and TQFN packages and is fully specified over the -40°C to +85°C extended temperature range.

put chattering associated with battery-voltage monitors.

### Features

- 1% Accurate Threshold Specified Over Full **Temperature Range**
- Dual-/Triple-/Quad, Low-Battery Output Options
- Low 5.7µA Battery Current
- Open-Drain or Push-Pull Outputs
- Fixed or Adjustable Hysteresis
- Low Input Bias Current
- Guaranteed Valid Low-Battery-Output Logic State Down to VBATT = 1.05V
- Reverse-Battery Protection
- Immune to Short Battery Transients
- Fully Specified from -40°C to +85°C
- Small TDFN and TQFN Packages

PART	TEMP RANGE	PIN-PACKAGE
MAX6782TE_+	-40°C to +85°C	16 TQFN-EP*
MAX6783TE_+	-40°C to +85°C	16 TQFN-EP*
MAX6784TC_+	-40°C to +85°C	12 TQFN-EP*
MAX6785TC_+	-40°C to +85°C	12 TQFN-EP*

**Ordering Information** 

#### Ordering Information continued at end of data sheet.

+Denotes a lead(Pb)-free/RoHS-compliant package. \*EP = Exposed pad.

The MAX6782/MAX6783/MAX6784/MAX6785 are available with factory-trimmed hysteresis. Specify trim by replacing " " with "A" for 0.5%, "B" for 5%, or "C" for 10% hysteresis.

Pin	Configuration and	Typical	Operating	Circuit appear at
end	of data sheet.			

### Selector Guide

			1			
PART	MONITOR LEVEL	LBO OUTPUT	ov	ŌV	OUTPUT TYPE	HYSTERESIS
MAX6782TE_+	4	Quad	_	_	Push-Pull	Fixed/Adj
MAX6783TE_+	4	Quad	_	_	Open Drain	Fixed/Adj
MAX6784TC_+	3	Triple	_	_	Push-Pull	Fixed/Adj
MAX6785TC_+	3	Triple	_	_	Open Drain	Fixed/Adj
MAX6786TA+	2	Dual	_	_	Push-Pull	Adj
MAX6787TA+	2	Dual	_	_	Open Drain	Adj
MAX6788TA+	2	Dual	_	_	Push-Pull/Open Drain	Adj
MAX6789TB+	4	_	Single	Single	Push-Pull	—
MAX6790TB+	4	_	Single	Single	Open Drain	_

Note: All devices are available in tape and reel in 2.5k increments. For tape and reel orders, add a "T" after the "+" to complete the part number

Maxim Integrated Products 1

MAX6782-MAX6790

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

Applications

(Single-Cell Li+ or Multicell NiMH, NiCd, Alkaline) Cell Phones/Cordless Phones

Battery-Powered Systems

Pagers Portable Medical Devices PDAs **Electronic Toys MP3** Players

### **ABSOLUTE MAXIMUM RATINGS**

(All voltages referenced to GND.)

(	
BATT	0.3V to +6V
IN1–IN4, LBH1, LBL1,	
LBH2, LBL20.3V to Min ((VBATT	+ 0.3V) and +6V)
HADJ1-HADJ4, REF0.3V to Min ((VBATT	
LBO1–LBO4 (push-pull)0.3V to Min ((VBATT	+ 0.3V) and $+ 6V$ )
LBO1–LBO4 (open drain)	0.3V to +6V
Input Current (all pins)	20mA
Output Current (all pins)	20mA

Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )
8-Pin TDFN (derate 23.8mW/°C above +70°C)
10-Pin TDFN (derate 24.4mW/°C above +70°C)1951mW
12-Pin Thin QFN (derate 16.7mW/°C above +70°C)1333mW
16-Pin Thin QFN (derate 20.8mW/°C above +70°C)1667mW
Operating Temperature Range40°C to +85°C
Junction Temperature+150°C
Storage Temperature Range65°C to +150°C
Lead Temperature (soldering, 10s)+300°C
Soldering Temperature (reflow)+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

 $(V_{BATT} = 1.6V \text{ to } 5.5V, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise specified. Typical values are at } T_A = +25^{\circ}\text{C}.)$  (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
Operating Voltage Range		$T_A = 0^{\circ}C$ to $+70^{\circ}C$	1.05		5.5	V	
(Note 2)	2) VBATT 1		1.2		5.5		
Supply Current	1-	V <sub>BATT</sub> = 3.7V, no load		6.3	10	μA	
Supply Current	IQ	V <sub>BATT</sub> = 1.8V, no load		5.7		μA	
Startup Time (Note 3)		VBATT rising from 0 to 1.6V			5	ms	
MAX6782/MAX6783/MAX6784/MA	AX6785						
		0.5% hysteresis (A version)	0.5994	0.6055	0.6115		
IN_ Falling Threshold (Note 4)	VINF	5% hysteresis (B version)	0.5723	0.5781	0.5839	V	
		10% hysteresis (C version)	0.5422	0.5477	0.5531		
IN_ Rising Threshold (Note 4)	VINR		0.6024	0.6085	0.6146	V	
IN_, HADJ_ Input Leakage Current		$V_{IN_{,}} V_{HADJ_{}} \ge 0.3V$			5	nA	
Reference Output	VREF		0.6024	0.6085	0.6146	V	
Reference Load Regulation		I <sub>REF</sub> = 0 to 1mA		0.3		mV/mA	
Reference Temperature Coefficient	TEMPCO			15		ppm/°C	
Reference Short-Circuit Current				20		mA	
Hysteresis Adjustment Range			0.4		V <sub>REF</sub>	V	
Hysteresis Adjustment Logic Low	VHALL				0.05	V	
Hysteresis Adjustment Logic High	Vhalh		0.17			V	
MAX6786/MAX6787/MAX6788	•	•	•				
LBL_, LBH_ Threshold	V <sub>TH</sub>		0.6024	0.6085	0.6146	V	
LBL_, LBH_ Input Leakage Current		V <sub>LBL</sub> , V <sub>LBH</sub> _≥0.3V			5	nA	

### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{BATT} = 1.6V \text{ to } 5.5V, T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise specified. Typical values are at } T_A = +25^{\circ}C.)$  (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
MAX6782–MAX6788			•			
LBO_ Propagation Delay	tpD	±100mV overdrive		30		μs
		V <sub>BATT</sub> ≥ 1.2V, I <sub>SINK</sub> = 100µA			0.3	V
LBO_ Output Low Voltage (Push- Pull or Open Drain)	V <sub>OL</sub>	V <sub>BATT</sub> ≥ 2.7V, I <sub>SINK</sub> = 1.2mA			0.3	V
Fuil of Open Drain)		V <sub>BATT</sub> ≥ 4.5V, I <sub>SINK</sub> = 3.2mA			0.4	V
		$V_{BATT} \ge 1.6V, I_{SOURCE} = 10\mu A$	0.8 x V <sub>BATT</sub>			V
LBO_ Output High Voltage (Push-Pull) (Note 5)	V <sub>OH</sub>	$V_{BATT} \ge 2.7V$ , $I_{SOURCE} = 500\mu A$	0.8 x V <sub>BATT</sub>			V
		$V_{BATT} \ge 4.5V$ , $I_{SOURCE} = 800\mu A$	0.8 x V <sub>BATT</sub>			V
LBO_ Output Leakage Current (Open Drain)		Output not asserted, $V_{LBO_{-}} = 0$ or 5V			500	nA
MAX6789/MAX6790			-			
IN_ Rising Threshold	V <sub>TH+</sub>		0.6024	0.6085	0.6146	V
IN_ Hysteresis				31		mV
IN_ Input Leakage Current		$V_{IN} \ge 0.3V$			5	nA
OV, OV Delay Time	tpD	±100mV overdrive		30		μs
		$V_{BATT} \ge 1.6V$ , $I_{SINK} = 100\mu A$ , output asserted			0.3	
OV Output Low Voltage (Push- Pull or Open Drain)	V <sub>OL</sub>	$V_{BATT} \ge 2.7V$ , $I_{SINK} = 1.2mA$ , output asserted			0.3	V
		$V_{BATT} \ge 4.5V$ , $I_{SINK} = 3.2mA$ , output asserted			0.4	
		$V_{BATT} \ge 1.2V$ , $I_{SOURCE} = 10\mu A$ , output not asserted	0.8 x V <sub>BATT</sub>			
OV Output High Voltage (Push- Pull) (Note 5)	Voh	$V_{BATT} \ge 2.7V$ , $I_{SOURCE} = 500\mu$ A, output not asserted	0.8 x V <sub>BATT</sub>			V
		$V_{BATT} \ge 4.5V$ , $I_{SINK} = 800\mu A$ , output not asserted	0.8 x V <sub>BATT</sub>			
OV Output Leakage Current (Open Drain)		Output not asserted, $V_{OV}$ , $V_{\overline{OV}} = 0$ or 5V			500	nA
		$V_{BATT} \ge 1.2V$ , $I_{SINK} = 100\mu A$ , output not asserted			0.3	
OV Output Low Voltage (Push-Pull or Open Drain)	Vol	$V_{BATT} \ge 2.7V$ , $I_{SINK} = 1.2mA$ , output not asserted			0.3	V
		$V_{BATT} \ge 4.5V$ , $I_{SINK} = 3.2mA$ , output not asserted			0.4	

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### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{BATT} = 1.6V \text{ to } 5.5V, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise specified. Typical values are at } T_A = +25^{\circ}\text{C}.)$  (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
		$V_{BATT} \ge 1.6V$ , $I_{SOURCE} = 10\mu A$ , output asserted	0.8 x V <sub>BATT</sub>			
OV Output High Voltage (Push- Pull ) (Note 5)	V <sub>OH</sub>	$V_{BATT} \ge 2.7V$ , $I_{SOURCE} = 500\mu A$ , output asserted	0.8 x V <sub>BATT</sub>			V
		$V_{BATT} \ge 4.5V$ , $I_{SOURCE} = 800\mu$ A, output asserted	0.8 x V <sub>BATT</sub>			
OV Output Leakage Current (Open Drain)		Output asserted, $V_{OV} = 0$ or 5V			500	nA
CLEAR Input Low Voltage	V <sub>IL</sub>				0.3 x V <sub>BATT</sub>	V
CLEAR Input High Voltage	VIH		0.7 x V <sub>BATT</sub>			V
CLEAR Pullup Resistance			25		80	kΩ
CLEAR Minimum Pulse Width			1			μs
CLEAR Delay Time	tCLD			300		ns

**Note 1:** Devices are tested at  $T_A = +25^{\circ}C$  and guaranteed by design for  $T_A = T_{MIN}$  to  $T_{MAX}$  as specified.

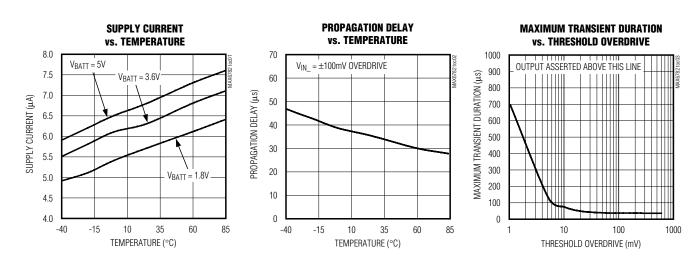
Note 2: Operating voltage range ensures low battery output is in the correct state. Minimum battery voltage for electrical specification is 1.6V.

Note 3: Reference and threshold accuracy is only guaranteed after the startup time. Startup time is guaranteed by design.

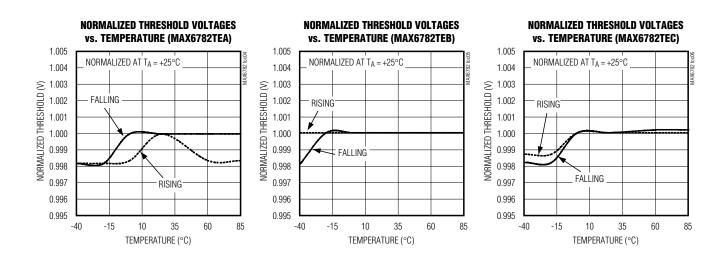
**Note 4:** The rising threshold is guaranteed to be higher than the falling threshold.

Note 5: The source current is the total source current from all outputs.

**Typical Operating Characteristics** 



 $(V_{BATT} = 3.6V, T_A = +25^{\circ}C, unless otherwise noted.)$ 





 $V_{BATT} = 5.0V$ 

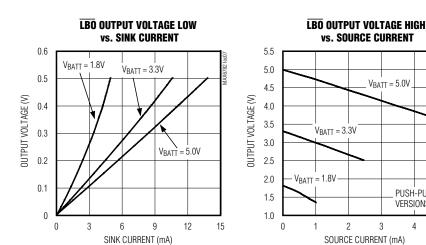
3

PUSH-PULL

VERSIONS

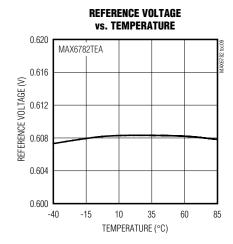
4

5



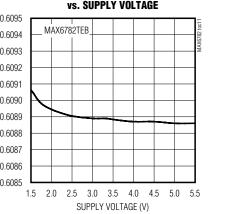
 $(V_{BATT} = 3.6V, T_A = +25^{\circ}C, unless otherwise noted.)$ 

### **Typical Operating Characteristics (continued)**

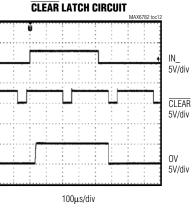


**REFERENCE VOLTAGE** vs. REFERENCE CURRENT 0.65 0.6095 MAX6782TEB 0.64 0.6094 0.63 0.6093 0.62

REFERENCE CURRENT (mA)



**REFERENCE VOLTAGE** 





0.61

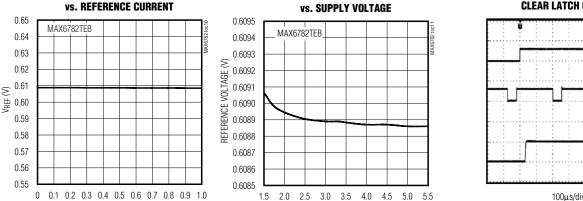
0.59

0.58

0.57

0.56

S



### \_Pin Description

#### PIN FUNCTION MAX6782/ NAME MAX6784/ MAX6783 MAX6785 Battery Monitor Input 2. Connect to an external resistive divider to set the trip 1 1 IN2 threshold for monitor 2. Battery Monitor Input 3. Connect to an external resistive divider to set the trip 2 2 IN3 threshold for monitor 3. Battery Monitor Input 4. Connect to an external resistive divider to set the trip З IN4 threshold for monitor 4 Reference Output. REF can source up to 1mA. REF does not require an external REF 4 3 bypass capacitor for stability. Keep the capacitance from REF to GND below 50pF. Hysteresis Adjustment Input 1. Connect HADJ1 to GND to select an internal preset hysteresis option. 5 4 HADJ1 Connect a resistive divider from REF to HADJ1 and to GND to externally adjust the hysteresis for IN1 from its internal preset hysteresis (see Figure 6). Hysteresis Adjustment Input 2. Connect HADJ2 to GND to select an internal preset hysteresis option. HADJ2 6 5 Connect a resistive divider from REF to HADJ2 and to GND to externally adjust the hysteresis for IN2 from its internal preset hysteresis (see Figure 6). Hysteresis Adjustment Input 3. Connect HADJ3 to GND to select an internal preset hysteresis option. 7 6 HADJ3 Connect a resistive divider from REF to HADJ3 and to GND to externally adjust the hysteresis for IN3 from its internal preset hysteresis (see Figure 6). Hysteresis Adjustment Input 4. Connect HADJ4 to GND to select an internal preset hysteresis option. HADJ4 8 Connect a resistive divider from REF to HADJ4 and to GND to externally adjust the hysteresis for IN4 from its internal preset hysteresis (see Figure 6). Active-Low, Low-Battery Output 4. LBO4 asserts when VIN4 falls below the falling LBO4 9 threshold voltage. $\overline{LBO4}$ deasserts when V<sub>IN4</sub> exceeds the rising threshold voltage. Active-Low, Low-Battery Output 3. LBO3 asserts when VIN3 falls below the falling 10 7 I BO3 threshold voltage. $\overline{\text{LBO3}}$ deasserts when $V_{\text{IN3}}$ exceeds the rising threshold voltage. Active-Low, Low-Battery Output 2. LBO2 asserts when VIN2 falls below the falling LBO2 11 8 threshold voltage. $\overline{LBO2}$ deasserts when V<sub>IN2</sub> exceeds the rising threshold voltage. Active-Low, Low-Battery Output 1. LBO1 asserts when VIN1 falls below the falling 9 LBO1 12 threshold voltage. $\overline{LBO1}$ deasserts when V<sub>IN1</sub> exceeds the rising threshold voltage. Battery Input. Power supply to the device. For better noise immunity, bypass BATT 10 BATT 13 to GND with a 0.1µF capacitor as close to the device as possible. 14 GND Ground 11 N.C. No Connection. Not internally connected. 15 \_\_\_\_ Battery Monitor Input 1. Connect to an external resistive divider to set the trip 16 12 IN1 threshold for monitor 1. Exposed Pad. Connect EP to the ground plane. Do not use EP as the only ground EΡ connection.

### MAX6782/MAX6783/MAX6784/MAX6785



### Pin Description (continued)

### MAX6786/MAX6787/MAX6788

PIN	NAME	FUNCTION
1	LBL1	Falling Trip Level Input 1. Connect to an external resistive divider to set the falling trip level.
2	LBH1	Rising Trip Level Input 1. Connect to an external resistive divider to set the rising trip level.
3	LBL2	Falling Trip Level Input 2. Connect to an external resistive divider to set the falling trip level.
4	LBH2	Rising Trip Level Input 2. Connect to an external resistive divider to set the rising trip level.
5	GND	Ground
6	LBO2	Active-Low, Low-Battery Output 2. $\overline{LBO2}$ asserts when V <sub>LBL2</sub> falls below the falling threshold voltage. $\overline{LBO2}$ deasserts when V <sub>LBH2</sub> exceeds the rising threshold voltage.
7	LBO1	Active-Low, Low-Battery Output 1. $\overline{LBO1}$ asserts when V <sub>LBL1</sub> falls below the falling threshold voltage. $\overline{LBO1}$ deasserts when V <sub>LBH1</sub> exceeds the rising threshold voltage.
8	BATT	Battery Input. Power supply to the device. For better noise immunity, bypass BATT to GND with a $0.1 \mu F$ capacitor as close to the device as possible.
_	EP	Exposed Pad. Connect EP to the ground plane. Do not use EP as the only ground connection.

### MAX6789/MAX6790

PIN	NAME	FUNCTION
1	IN1	Overvoltage Monitor Input 1
2	IN2	Overvoltage Monitor Input 2
3	IN3	Overvoltage Monitor Input 3
4	IN4	Overvoltage Monitor Input 4
5	GND	Ground
6	CLEAR	Active-Low Clear Input. $\overline{OV}$ and OV do not latch when an overvoltage fault is detected if $\overline{CLEAR}$ is held low. CLEAR has an internal pullup resistor to BATT.
7	N.C.	No Connection. Not internally connected.
8	ŌV	Active-Low Overvoltage Output. When any of the inputs (V <sub>IN_</sub> ) exceeds its respective rising threshold voltage, $\overline{OV}$ asserts and stays asserted until $\overline{CLEAR}$ is pulled low or the power to the device is cycled. $\overline{OV}$ does not latch when an overvoltage fault is detected if $\overline{CLEAR}$ is held low.
9	OV	Active-High Overvoltage Output. Inverse of OV.
10	BATT	Battery Input. Power supply to the device. For better noise immunity, bypass BATT to GND with a $0.1 \mu F$ capacitor as close to the device as possible.
_	EP	Exposed Pad. Connect EP to the ground plane. Do not use EP as the only ground connection.

### **Detailed Description**

The MAX6782–MAX6788 are designed to monitor two to four battery levels (1% accuracy) and assert an active-low output indicator when the monitored voltage level falls below the user-set threshold. Each battery level is associated with an independent open-drain or push-pull output. Each of these independent outputs can be used to provide low battery warnings at different voltage levels. Each of these monitored levels offers fixed or adjustable hysteresis in order to prevent the output from chattering as the battery recovers from the lighter loads. The MAX6782–MAX6785 also feature reference outputs that can source up to 1mA.

The MAX6789/MAX6790 monitor four overvoltage conditions and assert the complementary overvoltage outputs when any voltage at the inputs exceeds its respective threshold. The MAX6789/MAX6790 allow each trip threshold to be set with external resistors. These devices also feature a latch and a clear function.

Figures 1, 2, and 3 show the simplified block diagrams for the MAX6782–MAX6790. See the *Selector Guide*.



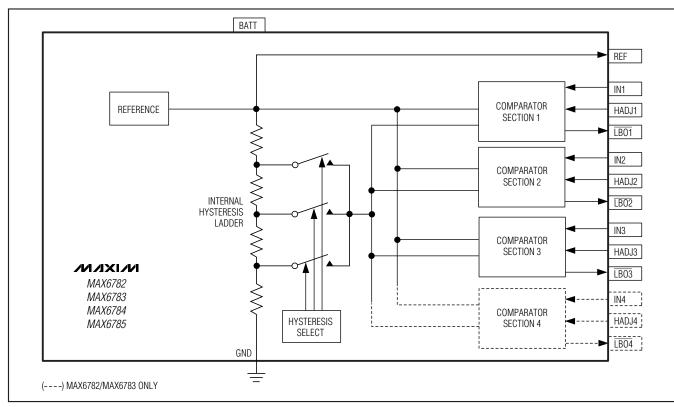


Figure 1. MAX6782–MAX6785 Block Diagram

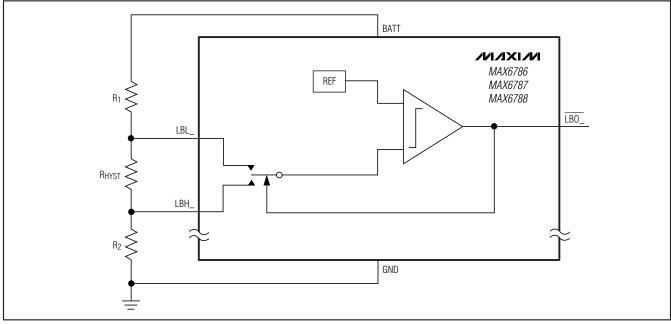


Figure 2. MAX6786/MAX6787/MAX6788 Block Diagram



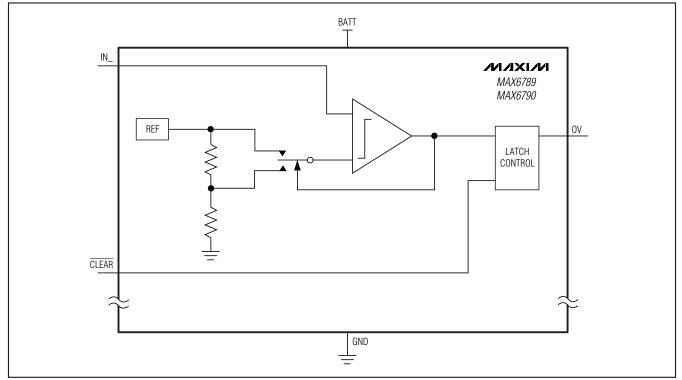


Figure 3. MAX6789/MAX6790 Block Diagram

#### Low-Battery/Overvoltage Output

All devices are offered with either push-pull or opendrain outputs (see the *Selector Guide*). The MAX6788 has one push-pull output and one open-drain output, configured as shown in Table 1.

### Table 1. MAX6788 Outputs

DEVICE	LB01	LBO2
MAX6788	Push-Pull	Open Drain

All open-drain outputs require an external pullup resistor. The open-drain pullup resistor may be connected to an external voltage up to +6V, regardless of the voltage at BATT.

#### Hysteresis

Input hysteresis defines two thresholds, separated by the hysteresis voltage, configured so the output asserts when the input falls below the falling threshold, and deasserts only when the input rises above the rising threshold. Figures 4 and 5 show this graphically. Hysteresis removes, or greatly reduces, the possibility of the output changing state in response to noise or battery-terminal voltage recovery after load removal.

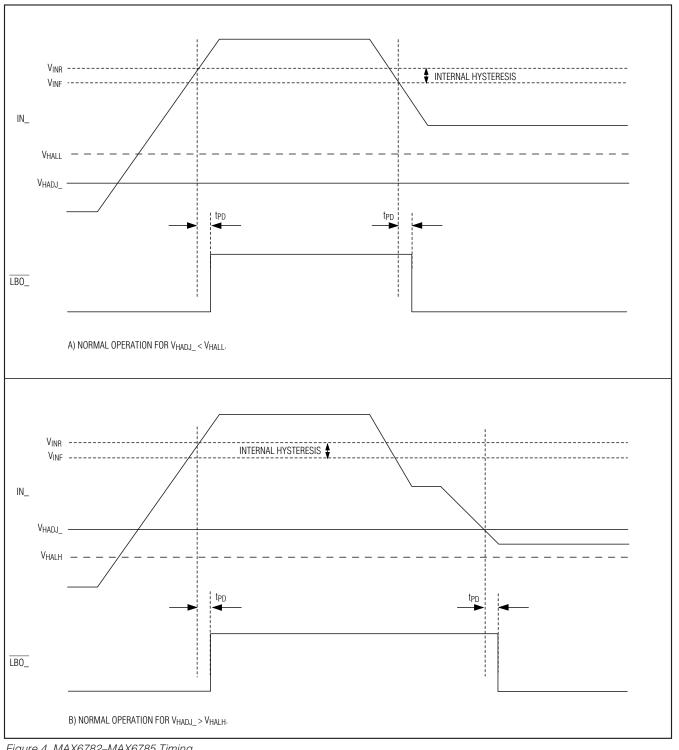


Figure 4. MAX6782–MAX6785 Timing



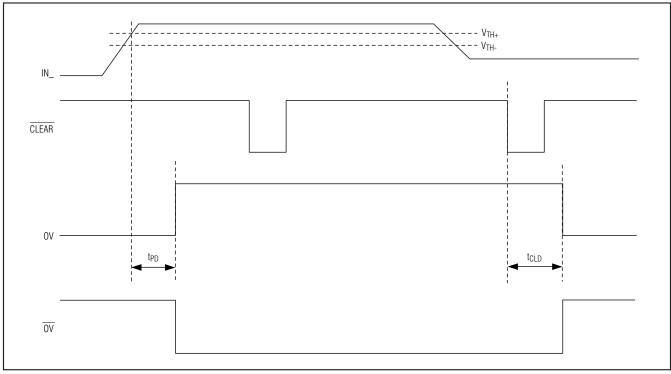


Figure 5. MAX6789/MAX6790 Timing

#### MAX6782-MAX6785 Hysteresis

#### Factory-Set Hysteresis

The MAX6782–MAX6785 have factory-set hysteresis for ease of use and reduced external parts count. For these devices the absolute hysteresis voltage is a percentage of the internally generated reference. The amount depends on the device option. "A" devices have 0.5% hysteresis, "B" devices have 5% hysteresis, and "C" devices have 10% hysteresis. Table 2 presents the threshold voltages for devices with factory-set hysteresis. For factory-set hysteresis, connect HADJ\_ to GND.

### Table 2. Typical Falling and Rising Thresholds for MAX6782–MAX6785 (HADJ\_ = GND)

DEVICE OPTION	PERCENT HYSTERESIS (%)	FALLING THRESHOLD (V <sub>INF</sub> ) (V)	RISING THRESHOLD (V <sub>INR</sub> ) (V)
A	0.5	0.6055	0.6085
В	5	0.5781	0.6085
С	10	0.5477	0.6085

#### Externally Adjusted Hysteresis

The MAX6782–MAX6785 can also be configured for externally adjustable hysteresis. Connect a resistive divider from REF to HADJ\_ and to GND (Figure 6) to set the hysteresis voltage. The hysteresis adjustment range is from 0.4V to VREF, and the voltage at HADJ\_ (V<sub>HADJ</sub>) must be set higher than Hysteresis Adjustment Logic High (V<sub>HALH</sub>) (Figure 4b). Note that if V<sub>HADJ</sub> is lower than Hysteresis Adjustment Logic Low (V<sub>HALL</sub>), these devices switch back to the internal factory-set hysteresis (Figure 4a).

#### MAX6786/MAX6787/MAX6788 Adjustable Hysteresis

The MAX6786/MAX6787/MAX6788 offer external hysteresis control through the resistive divider that monitors battery voltage. Figure 2 shows the connections for external hysteresis. See *Calculating an External Hysteresis Resistive Divider* (MAX6786/MAX6787/MAX6788) section for more information.



#### **Reference Output**

The reference output can provide up to 1mA of output current. The output is not buffered. Excessive loading affects the accuracy of the thresholds. An external capacitor is not required for stability and is stable for capacitive loads up to 50pF. In applications where the load or the supply can experience step changes, a capacitor reduces the amount of overshoot (undershoot) and improves the circuit's transient response. Place the capacitor as close to the device as possible for best performance.

### Applications Information

#### **Resistor-Value Selection**

Choosing the proper external resistors is a balance between accuracy and power use. The input to the voltage monitor, while high impedance, draws a small current, and that current travels through the resistive divider, introducing error. If extremely high resistor values are used, this current introduces significant error. With extremely low resistor values, the error becomes negligible, but the resistive divider draws more power from the battery than necessary, and shortens battery life. See Figure 6 and calculate the optimum value for R1 using:

$$R_1 = \frac{e_A \times V_{BATT}}{I_L}$$

where eA is the fraction of the maximum acceptable absolute resistive divider error attributable to the input leakage current (use 0.01 for 1%), VBATT is the battery voltage at which LBO should activate, and I<sub>L</sub> is the worst-case IN\_ leakage current, from the *Electrical Characteristics*. For example, for 0.5% error, a 2.8V battery minimum, and 5nA leakage, R<sub>1</sub> = 2.80M $\Omega$ . Calculate R<sub>2</sub> using:

$$R_2 = \frac{V_{INF} \times R_1}{V_{BATT} - V_{INF}}$$

where V<sub>INF</sub> is the falling threshold voltage from Table 2. Continuing the above example, and selecting V<sub>INF</sub> = 0.5477V (10% hysteresis device), R<sub>2</sub> =  $681k\Omega$ . There are other sources of error for the battery threshold, including resistor and input monitor tolerances.

#### Calculating an External Hysteresis Resistive Divider (MAX6782–MAX6785)

To set the hysteresis, place a resistive divider from REF to HADJ\_ as shown in Figure 6. The resistive divider sets voltage on HADJ\_, which controls the falling thresh-

old (V\_{INF}) on the associated IN\_ (the rising threshold (V\_{INR}) is fixed). See Table 2. Calculate R\_3 using:

$$R_3 = \frac{e_A \times V_{REF}}{I_L}$$

where eA is the fraction of the maximum acceptable absolute resistive divider error attributable to the input leakage current (use 0.01 for 1%),  $V_{REF}$  is the reference output voltage, and I<sub>L</sub> is the worst-case HADJ\_leakage current. Calculate R4 using:

$$R_4 = \frac{V_{INF} \times R_3}{V_{REF} - V_{INF}}$$

where  $V_{\text{INF}}$  is the desired falling voltage threshold. To calculate the percent hysteresis, use:

Hysteresis (%) = 
$$100 \times \frac{V_{INR} - V_{INF}}{V_{INR}}$$

where VINR is the rising voltage.

#### Calculating an External Hysteresis Resistive Divider (MAX6786/MAX6787/MAX6788)

Setting the hysteresis externally requires calculating three resistor values, as indicated in Figure 2. First calculate  $R_1$  using:

$$R_1 = \frac{e_A \times V_{BATT}}{I_L}$$

and R<sub>20</sub> using:

$$R_{20} = \frac{V_{TH} \times R_1}{V_{BATT} - V_{TH}}$$
 (as in the above example)

where  $R_{20} = R_2 + R_{HYST}$  determine the total resistivedivider current, I<sub>TOTAL</sub>, at the trip voltage using:

$$I_{\text{TOTAL}} = \frac{V_{\text{BATT}}}{R_1 + R_{20}}$$

Then, determine RHYST using:

$$R_{HYST} = \frac{V_{HYST}}{I_{TOTAL}}$$

where  $V_{HYST}$  is the required hysteresis voltage. Finally, determine  $R_2$  using:

$$R_2 = R_{20} - R_{HYST}$$

#### Monitoring a Battery Voltage Higher than the Allowable VBATT

For monitoring higher voltages, supply a voltage to BATT, which is within the specified supply range, and power the input resistive divider from the high voltage to be monitored. Do not exceed the Absolute Maximum Ratings.

#### **Maintaining Reference Accuracy**

Since the ground connection of the MAX6782–MAX6790 has a small series resistance, any current flowing into an output flows to ground and causes a small voltage to develop from the internal ground to GND. This has the effect of slightly increasing the reference voltage. To minimize the effect on the reference voltage, keep the total output sink current below 3mA.

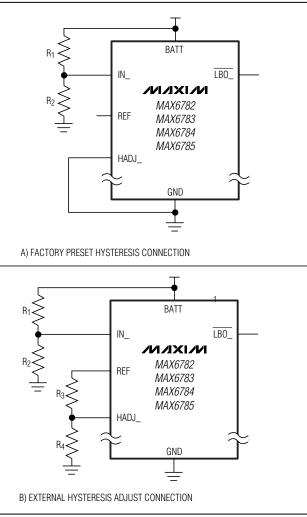


Figure 6. Internal Preset or Externally Adjusted Hysteresis Connection

### Adding External Capacitance to Reduce Noise and Transients

If monitoring voltages in a noisy environment, add a bypass capacitor of  $0.1\mu$ F from BATT to GND as close as possible to the device. For systems with large transients, additional capacitance may be required.

### **Reverse-Battery Protection**

To prevent damage to the device during a reverse-battery condition, connect the MAX6782–MAX6785 in the configuration shown in Figure 6a or 6b. For the internal reversebattery protection to function correctly on the MAX6782– MAX6790, several conditions must be satisfied:

- The connections to IN\_/LBL\_/LBH\_ must be made to the center node of a resistive divider going from BATT to GND. The Thevenin equivalent impedance of the resistive divider must not fall below  $1k\Omega$  in order to limit the current.
- HADJ\_ (MAX6782–MAX6785 only) must either be connected to GND or to the center node of a resistive divider going from REF to GND.
- The outputs may only be connected to devices powered by the same battery as the MAX6782-MAX6790.

Note that the MAX6782–MAX6790 will not protect other devices in the circuit.

### **Additional Application Circuit**

Figure 7 shows the MAX6786/MAX6787/MAX6788 in a typical two-battery-level monitoring circuit.

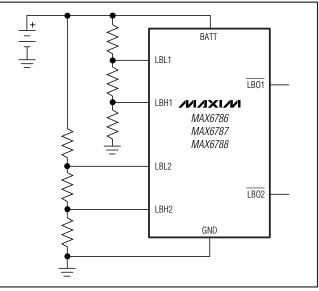
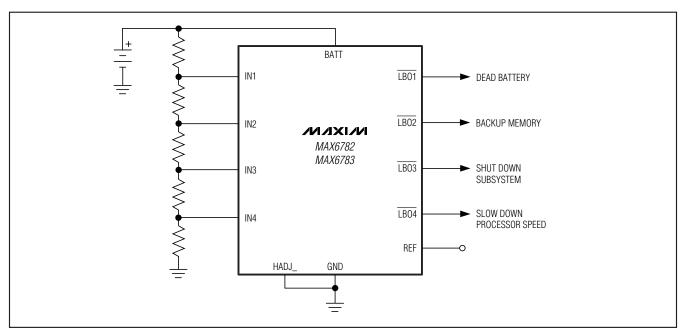


Figure 7. Two-Battery-Level Monitor Configuration

### \_Typical Operating Circuit



PART	TOP MARK	
MAX6782TEA+	+AEG	
MAX6782TEB+	+AEH	
MAX6782TEC+	+AEI	
MAX6783TEA+	+AEJ	
MAX6783TEB+	+AEK	
MAX6783TEC+	+AEL	
MAX6784TCA+	+AAV	
MAX6784TCB+	+AAW	
MAX6784TCC+	+AAX	
MAX6785TCA+	+AAY	
MAX6785TCB+	+AAZ	
MAX6785TCC+	+ABA	
MAX6786TA+	+APU	
MAX6787TA+	+APV	
MAX6788TA+	+APW	
MAX6789TB+	+AQI	
MAX6790TB+	+AQJ	

### **Top Marks**

### \_Ordering Information (continued)

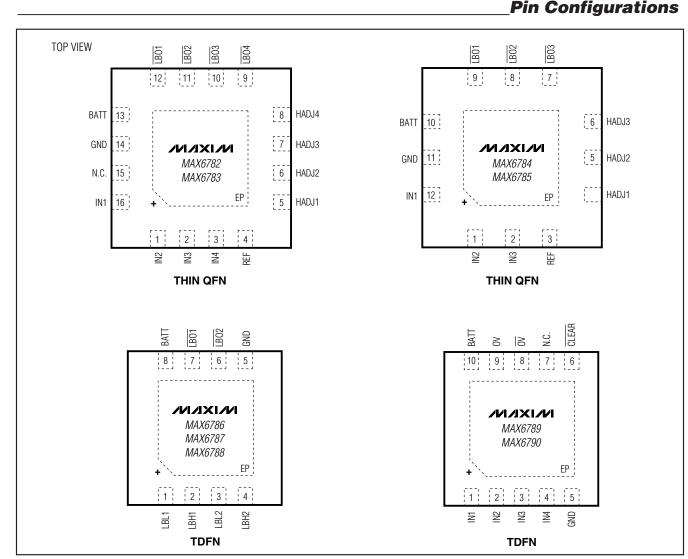
PART	TEMP RANGE PIN-PACKAGE	
MAX6786TA+T	-40°C to +85°C	8 TDFN-EP*
MAX6787TA+T	<b>AX6787</b> TA+T -40°C to +85°C 8 TDFN-EP*	
MAX6788TA+T	-40°C to +85°C	8 TDFN-EP*
MAX6789TB+T	-40°C to +85°C	10 TDFN-EP*
MAX6790TB+T	-40°C to +85°C	10 TDFN-EP*

+Denotes a lead-free/RoHS-compliant package.

\*EP = Exposed pad.

The MAX6782/MAX6783/MAX6784/MAX6785 are available with factory-trimmed hysteresis. Specify trim by replacing "\_" with "A" for 0.5%, "B" for 5%, or "C" for 10% hysteresis.





### Pin Configurations

### **Chip Information**

PROCESS: BICMOS

MAX6782-MAX6790

### Package Information

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
8 TDFN-EP	T833-3	<u>21-0137</u>
10 TDFN-EP	T1033-1	<u>21-0137</u>
12 TQFN-EP	T1233-1	<u>21-0136</u>
16 TQFN-EP	T1633-4	<u>21-0136</u>

### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	8/06	Initial release	—
1	10/06	Released the MAX6784, MAX6786–MAX6790.	1, 15
2	5/08	Updated the Pin Description tables.	7, 8
3	3/10	Updated the Absolute Maximum Ratings and the Electrical Characteristics table.	2

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